



ELECTRONICS, INC.
44 FARRAND STREET
BLOOMFIELD, NJ 07003
(973) 748-5089
<http://www.nteinc.com>

NTE1288 **Integrated Circuit** **Audio Power Amplifier, 10W** **for Car Radio**

Description:

The NTE1288 has improved performance with the same pin configuration as the NTE1232. The additional features of the NTE1232; very low number of external components, ease of assembly, space and cost saving, are maintained. The device provides a high output current capability (up to 3.5A), very low harmonic and cross distortion.

Complete safe operation is guaranteed due to protection against DC and AC short-circuit between all pins and GND, thermal over-range, load dump voltage surge up to 40V, polarity inversion and fortuitous open ground.

Absolute Maximum Ratings:

Peak Supply Voltage (50ms), V_{CC}	40V
DC Supply Voltage, V_{CC}	28V
OPERating Supply Voltage, V_{CC}	18V
Output Peak Current, I_O	
Repetitive	3.5A
Non-Repetitive	4.5A
Power Dissipation ($T_C = +90^\circ\text{C}$), P_{tot}	20W
Operating Junction Temperature Range, T_J	-40° to $+150^\circ\text{C}$
Storage Temperature Range, T_{stg}	-40° to $+150^\circ\text{C}$
Thermal Resistance, Junction-to-Case, R_{thJC}	3°C/W

Static Characteristics: ($T_A = +25^\circ\text{C}$, $V_{CC} = 14.4\text{V}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage	V_{CC}	8	–	18	V
Quiescent Output Voltage	Pin4 V_O	6.1	6.9	7.7	V
Quiescent Drain Current	Pin5 I_{CC}	–	44	50	mA

Dynamic Characteristics: ($T_A = +25^\circ\text{C}$, $V_{CC} = 14.4\text{V}$, $A_V = 40\text{dB}$ unless otherwise specified)

Parameter	Symbol	Test Conditions		Min	Typ	Max	Unit
Output Power	P _O	d = 10%, f = 1kHz	R _L = 4Ω	5.5	6.0	–	W
			R _L = 2Ω	9	10	–	W
			R _L = 3.2Ω	–	7.5	–	W
			R _L = 1.6Ω	–	12	–	W
Input Saturation Voltage	V _I			300	–	–	mV
Input Sensitivity	S	f = 1kHz, P _O = 500mW, R _L = 4Ω		–	14	–	mV
		P _O = 6W, R _L = 4Ω		–	55	–	mV
		P _O = 500mW, R _L = 2Ω		–	10	–	mV
		P _O = 10W, R _L = 2Ω		–	50	–	mV
Bandwidth (–3dB)	B	P _O = 1W, R _L = 4Ω		40 to 15,000			Hz
Harmonic Distortion	d	50mW ≤ P _O ≤ 4.5W, R _L = 4Ω, f = 1kHz		–	0.15	–	%
		50mW ≤ P _O ≤ 7.5W, R _L = 2Ω, f = 1kHz		–	0.15	–	%
Input Resistance (Pin1)	R _I	f = 1kHz		70	150	–	kΩ
Voltage Gain Open Loop	A _V	R _L = 4Ω, f = 1kHz		–	80	–	dB
Closed Loop				39.5	40.0	40.5	dB
Input Noise Voltage	V _n	B (–3dB) = 10Hz to 25kHz, B (–20dB) = 4Hz to 27kHz		–	1	5	μV
Input Noise Current	i _n	B (–3dB) = 10Hz to 25kHz, B (–20dB) = 4Hz to 27kHz		–	60	200	pA
Efficiency	η	f = 1kHz, P _O = 6W, R _L = 4Ω		–	69	–	%
		P _O = 10W, R _L = 2Ω		–	65	–	%
Supply Voltage Rejection	SVR	f = 100Hz, V _{ripple} = 500mV, R _G = 10kΩ, R _L = 4Ω		30	36	–	dB

